

# **UHF Variable Capacitance Diode**

### **FEATURES**

- Excellent linearity
- · Very small plastic SMD package.
- C28: 1.9 pF; ratio: 10
- · Low series resistance.

### **APPLICATIONS**

- Electronic tuning in UHF television tuners.
- · Radio upconversion concepts
- · VCO.

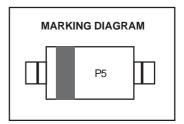
#### DESCRIPTION

The BB135 is a variable capacitance diode, fabricated in planar technology, and encapsulated in the SOD323 very small plastic SMD package.

The matched type, BB134 has the same specification.



**BB135** 



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### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT	
$V_R$	continuous reverse voltage	-	30	V	
l <sub>F</sub>	continuous forward current	-	20	mA	
T <sub>stg</sub>	storage temperature	<b>-</b> 55	+150	°C	
T <sub>j</sub>	operating junction temperature	<b>–</b> 55	+125	℃	

## **ELECTRICAL CHARACTERISTICS**

 $T_j = 25$  °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
lr	reverse current	V <sub>R</sub> = 30 V; see Fig.2	_	10	nA
		$V_R = 30 \text{ V}; T_j = 85 \text{ °C}; \text{ see Fig.2}$	_	200	nA
rs	diode series resistance	f = 470 MHz; note 1	_	0.75	Ω
Cd	diode capacitance	V <sub>R</sub> = 0.5 V; f = 1 MHz; see Figs 1 and 3	17.5	21	pF
		V <sub>R</sub> = 28 V;f = 1 MHz; see Figs 1 and 3	1.7	2.1	pF
Cd( 0.5V )	capacitance ratio	f = 1 MHz	8.9	12	
Cd (28V)					

### Note

1. VR is the value at which  $C_d = 9 pF$ .



### **BB135**

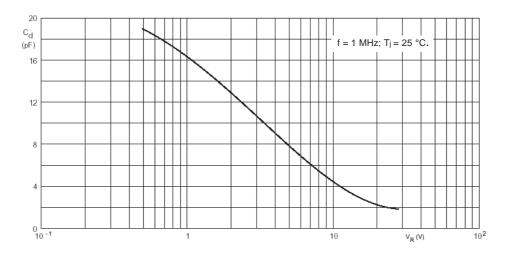


Fig.1 Diode capacitance as a function of reverse voltage; typical values.

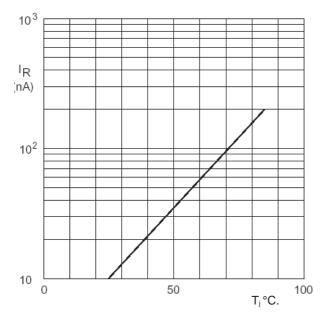


Fig.2 Reverse current as a function of junction temperature; maximum values.

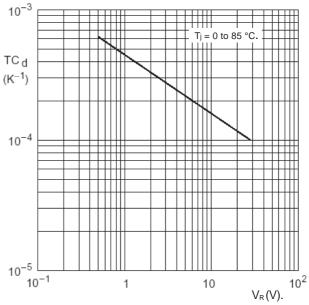


Fig.3 Temperature coefficient of diode capacitance as a function of reverse voltage; typical values.